

Product Overview

NVATS5A106PLZ: P-Channel Power MOSFET -40V, -33A, 25mΩ

For complete documentation, see the data sheet.

Automotive Power MOSFET designed for compact and efficient designs and including high thermal performance. ATPAK devices are Low on-resistance, High current capability and pin-compatible with DPAK(TO-252). AEC-Q101 qualified MOSFET and PPAP capable suitable for automotive applications.

Features

- · Low On-Resistance
- · High Current Capability
- 100% Avalanche Tested
- · AEC-Q101 qualified and PPAP capable
- ATPAK Package is Pin-Compatible with DPAK(TO-252)
- · RoHS compliance

Applications

- · Reverse Battery Protection for Automotive
- · Load Switch for Automotive
- · Automotive Front Lighting
- · Automotive Body Controllers

Benefits

- Minimizes Conduction Losses, Reduces Heat Dissipation
- · Robust Load Performance
- Safeguard Against Voltage Overstress Failures
- Suitable for Automotive Applications
- Enable Replace DPAK with ATPAK without Changing Land Patterns
- · Environmental Consideration

End Products

· Automotive (Head Light, Body Control)

Part Electrical Specifications																
Product	Compliance	Status	Chan nel Polari ty	Confi gurati on	V _{(BR)D} SS Min (V)	V _{GS} Max (V)	V _{GS(th)} Max (V)	I _D Max (A)	P _D Max (W)	$R_{DS(on)}$ Max @ $V_{GS} = 2.5 V$ (m Ω)	$R_{DS(on})$ Max @ $V_{GS} = 4.5 V$ (m Ω)	$R_{DS(on)}$ Max @ $V_{GS} = 10 \text{ V}$ (m Ω)	Q _g Typ @ V _{GS} = 4.5 V (nC)	Q _g Typ @ V _{GS} = 10 V (nC)	C _{iss} Typ (pF)	Pack age Type
NVATS5A106PLZT4G	AEC Qualified PPAP Capable Pb-free Halide free	Active	P- Chan nel	Singl e	-40	20	-2.6	-33	48	-	41	25	-	29	1380	DPA K (Singl e Gaug e) / ATPA K

For more information please contact your local sales support at www.onsemi.com.

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